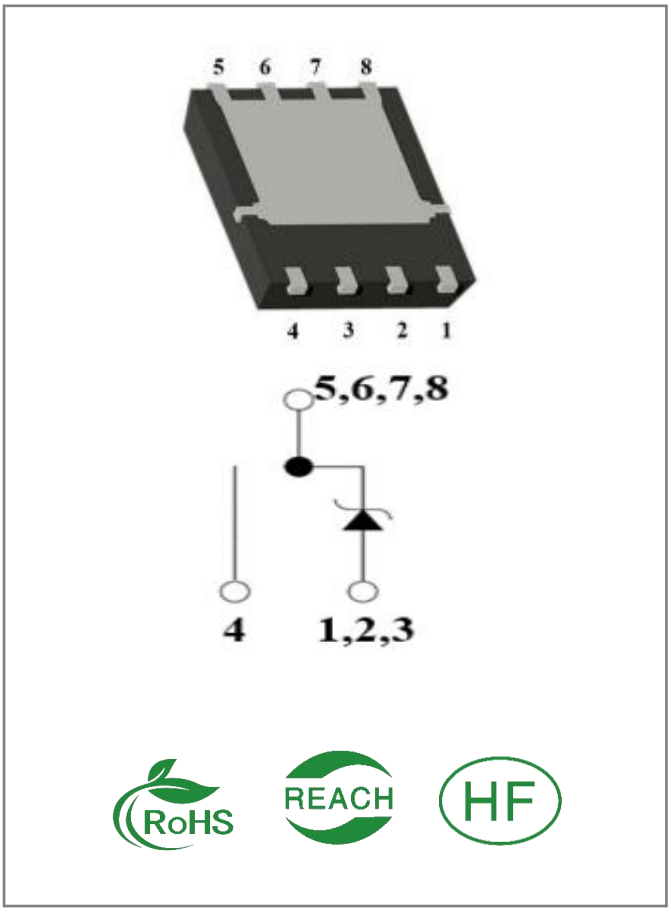
VRRM	IF (TC≤135℃)	QC
650V	8.5A	18nC



Applications:
- Switch Mode Power Supplies
- Power Factor Correction
- Motor drive, PV Inverter, Wind Power Station

Features:
- Zero Reverse Recovery Current
- Zero Forward Recovery Voltage
- Positive Temperature Coefficient on VF
- Temperature-independent Switching
- 175°C Operating Junction Temperature

Benefits:
- Replace Bipolar with Unipolar Device
- Reduction of Heat Sink Size
- Parallel Devices Without Thermal Runaway
- Essentially No Switching Losses

Ordering Information

Part Number	Package	Marking	Packing	Qty.
RSS06065G	DFN5*6	RSS06065G	Tape&reel	5000 PCS

Maximum Ratings (TJ= 25℃ unless otherwise specified)

Symbol	Parameter	Value	Unit	Test Conditions	Note
VRRM	Repetitive Peak Reverse Voltage	650	V	TC = 25℃	
VRSM	Surge Peak Reverse Voltage	650	V	TC = 25℃	
VR	DC Blocking Voltage	650	V	TC = 25℃	
IF	Forward Current	18.5 8.5 6	A	TC ≤ 25℃ TC ≤ 135℃ TC ≤ 150℃	Fig.3
IFSM	Non-Repetitive Forward Surge Current	70 65	A	TC = 25℃, tp = 10ms, Half Sine Wave TC = 110℃, tp = 10ms, Half Sine Wave	
IFRM	Repetitive Peak Forward Surge Current	55	A	TC = 25℃, tp = 10ms, Half Sine Wave	
Ptot	Power Dissipation	76	W	TC = 25℃	Fig.4
TC	Maximum Case Temperature	150	℃		
TJ,TSTG	Operating Junction and Storage Temperature	-55 to175	℃		

Electrical Characteristics (TJ= 25℃ unless otherwise specified)

Symbol	Parameter	Typ.	Max.	Unit	Test Conditions	Note
VF	Forward Voltage	1.34 1.67	1.5 -	V	IF = 6A, TJ = 25℃ IF = 6A, TJ = 175℃	Fig.1
IR	Reverse Current	1.2 4.5	50 -	μA	VR = 650V, TJ = 25℃ VR = 650V, TJ = 175℃	Fig.2
C	Total Capacitance	261 35 33	/	pF	VR = 1V, TJ = 25℃, f = 1MHz VR = 200V, TJ = 25℃, f = 1MHz VR = 400V, TJ = 25℃, f = 1MHz	Fig.5
QC	Total Capacitive Charge	18	/	nC	VR =400V,	Fig.6
Ec	Capacitance Stored Energy	2.9		uJ	VR =400V,	Fig.7

Thermal Characteristics (TJ= 25℃ unless otherwise specified)

Symbol	Parameter	Typ.	Unit	Note
RθJC	Thermal Resistance from Junction to Case	1.95	℃/W	Fig.8

Typical Feature Curve

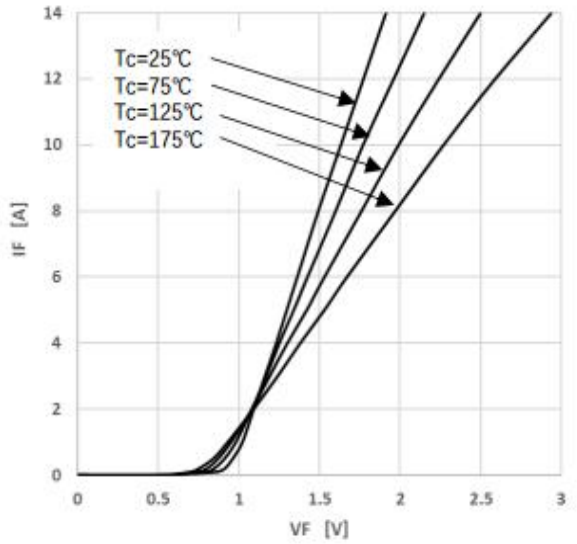


Figure 1 Forward Characteristics

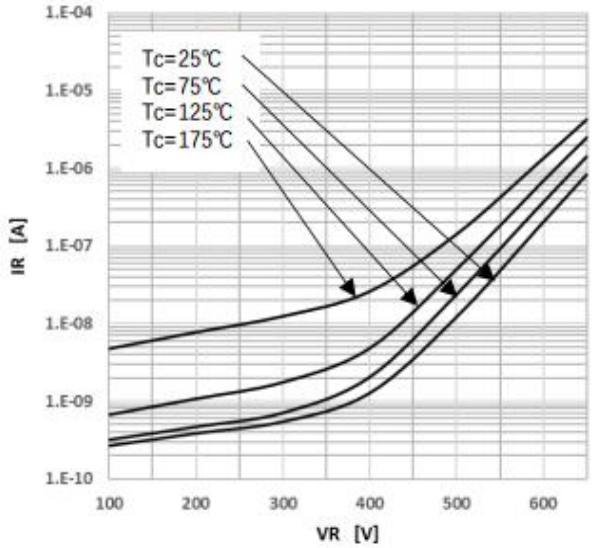


Figure 2 Reverse Characteristics

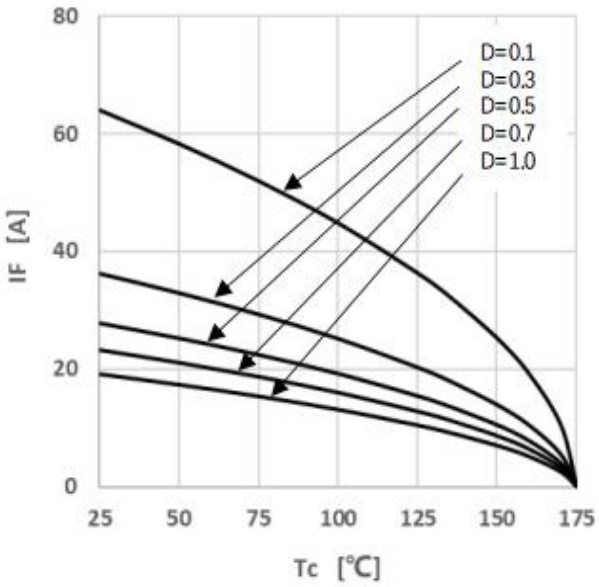


Figure 3 Peak Forward Current Derating

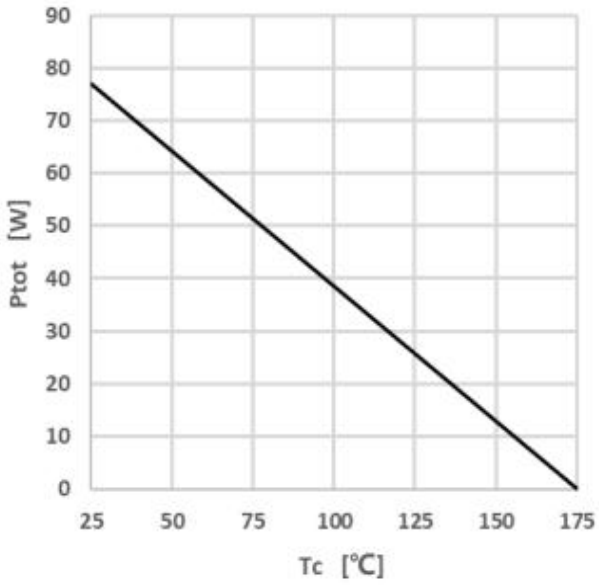


Figure 4 Power Dissipation

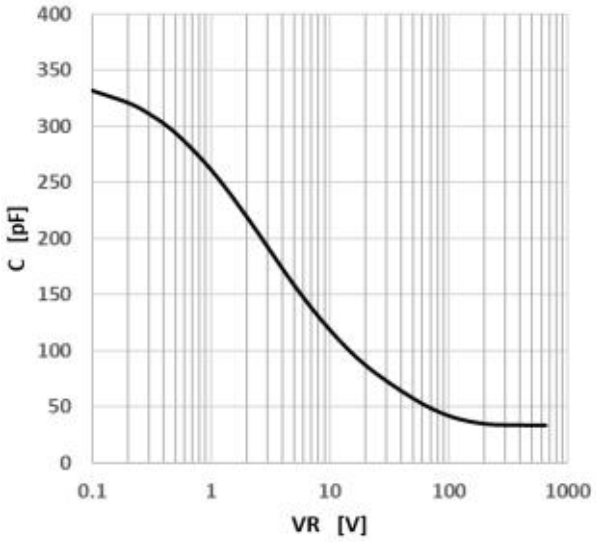


Figure 5 Capacitance vs. Reverse Voltage

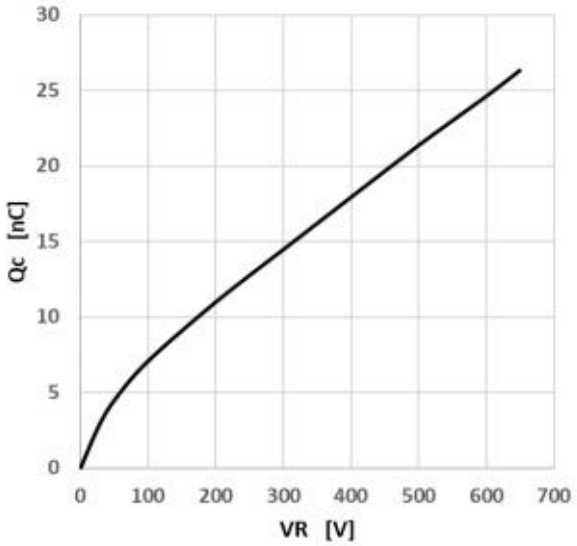


Figure 6 Capacitance Charge vs. Reverse Voltage

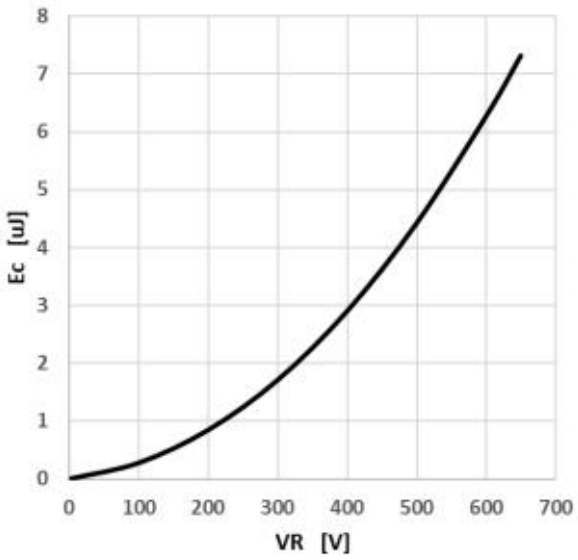


Figure 7 Capacitance Stored Energy

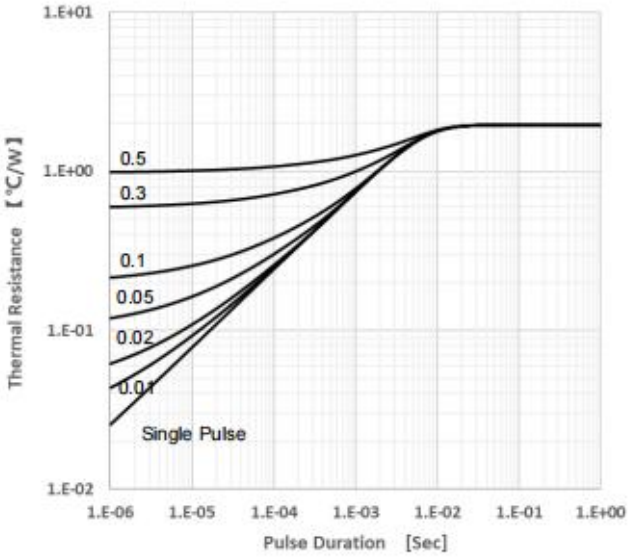
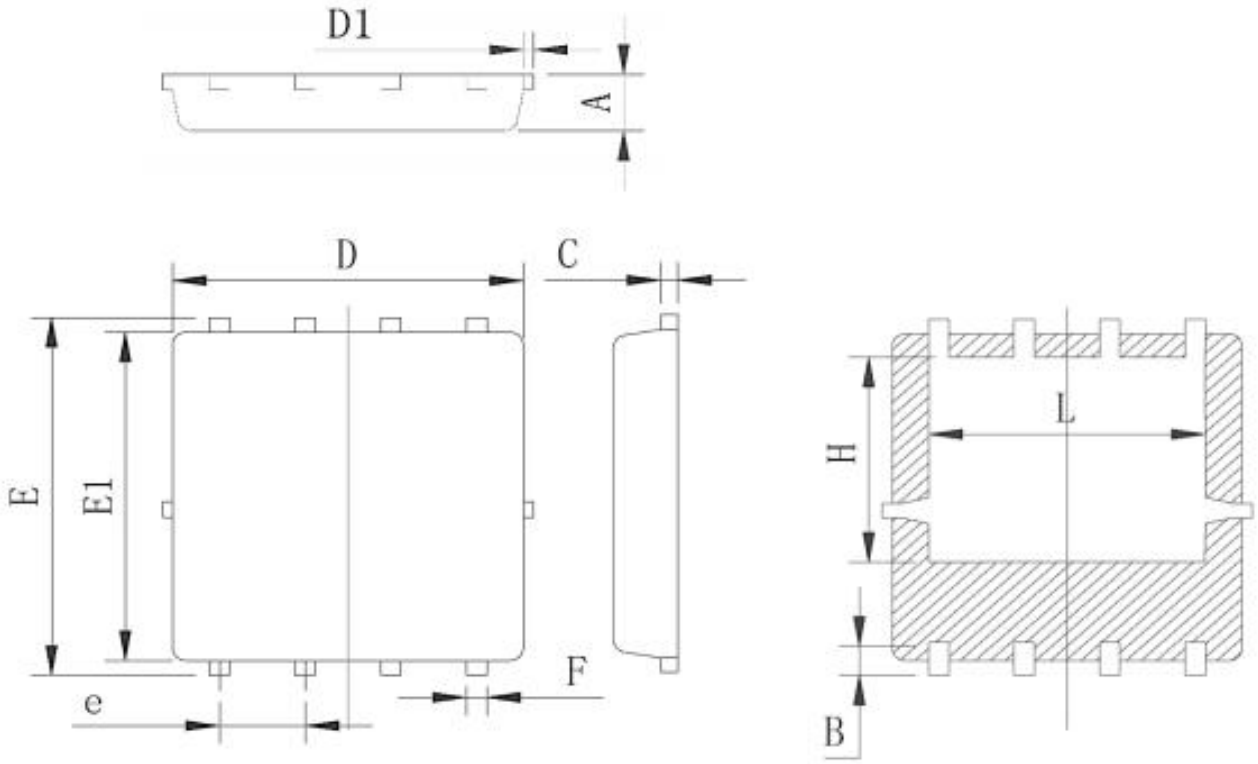


Figure 8 Transient Thermal Impedance

Package outline drawing(DFN5*6 Unit: mm)



Symbol	Min	Typ	Max
A	0.90	0.95	1.00
B	0.48	0.58	0.68
C	0.20	0.254	0.30
D	5.00	5.20	5.40
D1			0.15
E	5.90	6.05	6.20
E1	5.40	5.55	5.70
e	1.22	1.27	1.32
F	0.25	0.30	0.35
H	3.27	3.47	3.67
L	3.80	4.00	4.20

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